imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832 Email & Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China





PMCM650CUNE 20 V, Common Drain N-channel Trench MOSFET Rev. 1.0 — 8 November 2017 Pro

Product data sheet

1 **Product profile**

1.1 General description

N-channel enhancement mode common-drain dual Field-Effect Transistor (FET) in a 6 bumps Wafer Level Chip-Size Package (WLCSP) using Trench MOSFET technology.

1.2 Features and benefits

- · Common-drain type for bi-directional current flow
- · Low threshold voltage
- Ultra small package: 0.98 × 1.48 × 0.35 mm
- Trench MOSFET technology
- ElectroStatic Discharge (ESD) protection > 2 kV HBM

1.3 Applications

- Loadswitch
- Battery Protection
- Battery Management

1.4 Quick reference data

Table 1. Q	uick reference data					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{SS}	source-source voltage	T _j = 25 °C	-	-	20	V
V _{GS}	gate-source voltage		-8	-	8	V
Is	source current	T_{amb} = 25 °C; V_{GS} = 4.5 V; t ≤ 5 s ^[1]	-	-	5.3	А
Static cha	racteristics					
R _{SSon}	source-source on-state resistance	V_{GS} = 4.5 V; I _S = 3 A; T _j = 25 °C	-	40	52	mΩ

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm².

nexperia

20 V, Common Drain N-channel Trench MOSFET

2 Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
A1	G1	gate 1	1 2	S1 S2
A2	S1	source 1		
B1	S2	source 2	в	
B2	S1	source 1		
C1	S2	source 2		G1 G2 aaa-027241
C2	G2	gate 2	Transparent top view	

3 Ordering information

Table 3. Ordering information

Type number	Package	ackage						
	Name	Description	Version					
PMCM650CUNE	WLCSP6	wafer level chip-size package; 6 bumps (3 x 2)	WLCSP6_3-2					

4 Marking

Table 4. Marking codes	
Type number	Marking code
PMCM650CUNE	AH

20 V, Common Drain N-channel Trench MOSFET

Limiting values 5

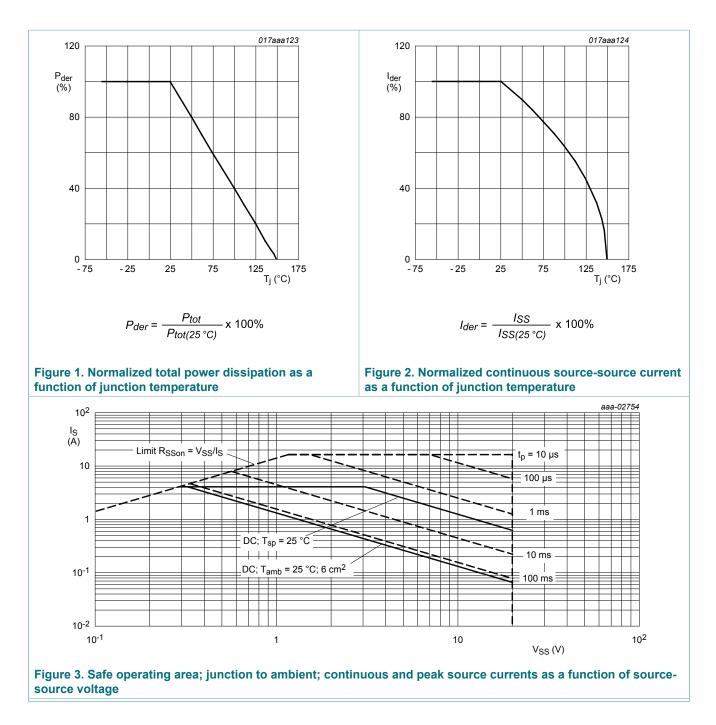
Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{SS}	source-source voltage	T _j = 25 °C		-	20	V
V _{GS}	gate-source voltage	T _j = 25 °C		-8	8	V
I _S	source current	T_{amb} = 25 °C; V_{GS} = 4.5 V; t ≤ 5 s	[1]	-	5.3	А
		T_{amb} = 25 °C; V_{GS} = 4.5 V	[1]	-	4.1	А
		T_{amb} = 100 °C; V_{GS} = 4.5 V	[1]	-	2.6	А
I _{SM}	peak source current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	16	A
P _{tot}	total power dissipation	T _{amb} = 25 °C	[2]	-	556	mW
		T _{amb} = 25 °C	[1]	-	1300	mW
		T _{sp} = 25 °C		-	12500	mW
Tj	junction temperature			-55	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C
Source-Foi	rward diode					
I _{FS}	source-forward current	T _{amb} = 25 °C	[1]	-	1.2	А

Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm². Device mounted on an FR4 PCB, single-sided copper; tin-plated and standard footprint. [1] [2]

PMCM650CUNE



20 V, Common Drain N-channel Trench MOSFET

6 Thermal characteristics

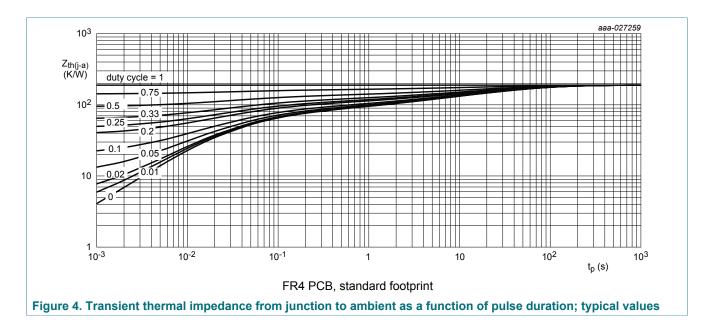
Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)} thermal resistance from j to ambient	thermal resistance from junction	in free air	[1]	-	180	225	K/W
	to ambient		[2]	-	65	85	K/W
			[3]	-	75	95	K/W
		in free air; t ≤ 5 s	[3]	-	45 55	55	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	5	10	K/W

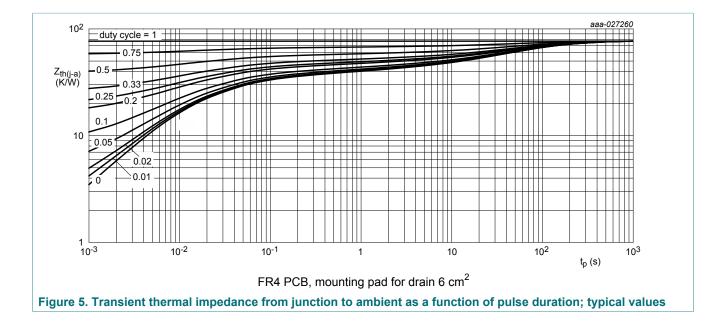
[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper; tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain, 4 layer, 1 cm².

[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 6 cm².



PMCM650CUNE



20 V, Common Drain N-channel Trench MOSFET

7 Characteristics

Table 7. Characteristics

 T_j = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristic					
V _{(BR)SS}	source-source breakdown voltage	$I_{\rm S}$ = 250 µA; $V_{\rm GS}$ = 0 V;	20	-	-	V
V _{GSth}	gate-source threshold voltage	I_D = 250 µA; V_{SS} = V_{GS}	0.4	0.7	0.9	V
I _{SSS}	source leakage current	V_{GS} = 0 V; V_{SS} = 20 V	-	-	1	μA
I _{GSS}	gate leakage current	V _{GS} = 8 V; V _{SS} = 0 V	-	-	10	μA
		V_{GS} = -8 V; V_{SS} = 0 V	-	-	-10	μA
		V _{GS} = 4.5 V; V _{SS} = 0 V	-	-	1	μA
		V_{GS} = -4.5 V; V_{SS} = 0 V	-	-	-1	μA
		V_{GS} = 2.5 V; V_{SS} = 0 V	-	-	200	nA
		V_{GS} = -2.5 V; V_{SS} = 0 V	-	-	-200	nA
R _{SSon}	source-source on-state	V_{GS} = 4.5 V; I _S = 3 A; T _j = 25 °C	-	40	52	mΩ
	resistance	V _{GS} = 4.5 V; I _S = 3 A; T _j = 150 °C	-	55	71	mΩ
		V_{GS} = 2.5 V; I _S = 2 A; T _j = 25 °C	-	50	62	mΩ
		V_{GS} = 1.8 V; I _S = 1 A; T _j = 25 °C	-	63	95	mΩ
9 _{fs}	forward transconductance	V _{GS} = 4.5 V; I _S = 3 A	-	22	-	S
R _G	gate resistance	f = 1 MHz	-	6.6	-	Ω
Dynamic (characteristics					
Q _{G(tot)}	total gate charge	V_{SS} = 10 V; I _S = 3 A; V_{GS} = 4.5 V	-	9	13	nC
Q _{GS}	gate-source charge		-	0.7	-	nC
Q _{GD}	gate-drain charge		-	2.9	-	nC
C _{iss}	input capacitance	V_{SS} = 10 V; f = 1 MHz; V_{GS} = 0 V	-	480	-	pF
C _{oss}	output capacitance		-	96	-	pF
C _{rss}	reverse transfer capacitance		-	96	-	pF
t _{d(on)}	turn-on delay time	V _{SS} = 10 V; I _S = 3 A;	-	6	-	ns
t _r	rise time	V_{GS} = 4.5 V; $R_{G(ext)}$ = 6 Ω	-	20	-	ns
t _{d(off)}	turn-off delay time		-	39	-	ns
t _f	fall time		-	15	-	ns
Source-Fo	oward diode	· · · · · ·	1			
V _{FS}	source-forward voltage	$V_{G1S1} = 0 V$; $V_{G2S2} = 4.5 V$; $I_{S} = 1.2 A$	-	0.7	1.2	V

PMCM650CUNE

20 V, Common Drain N-channel Trench MOSFET

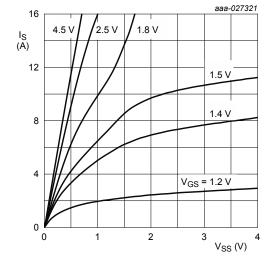
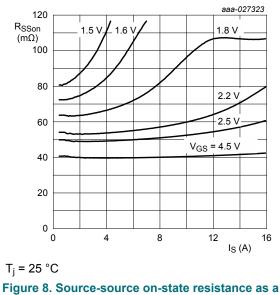




Figure 6. Output characteristics: source current as a function of source-source voltage; typical values





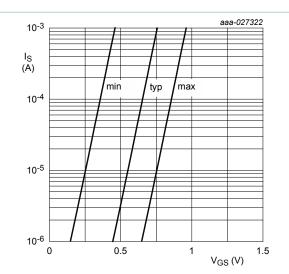
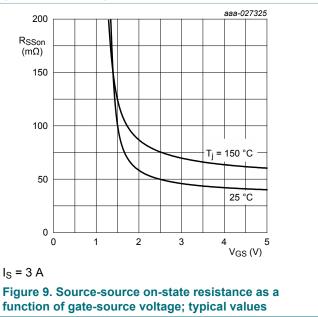
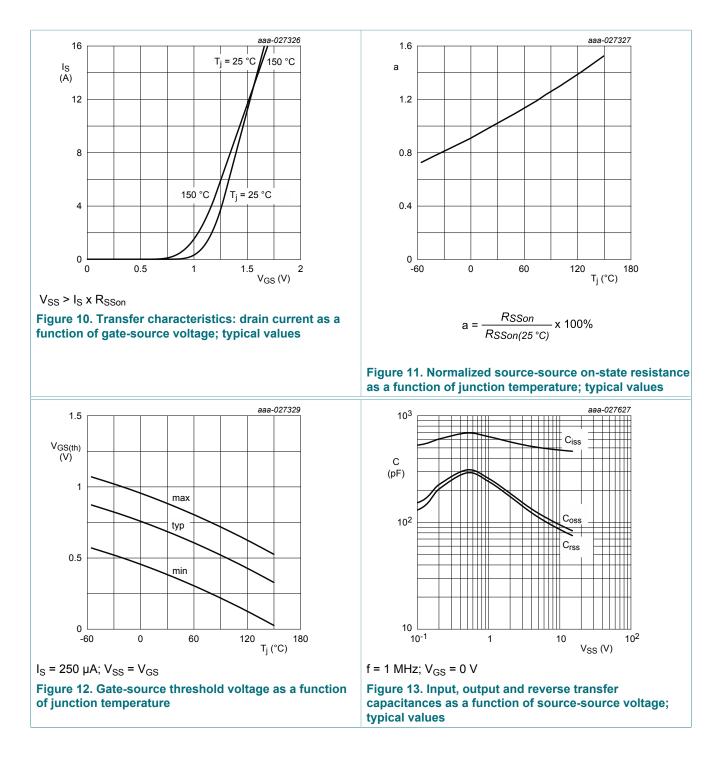




Figure 7. Sub-threshold source current as a function of gate-source voltage

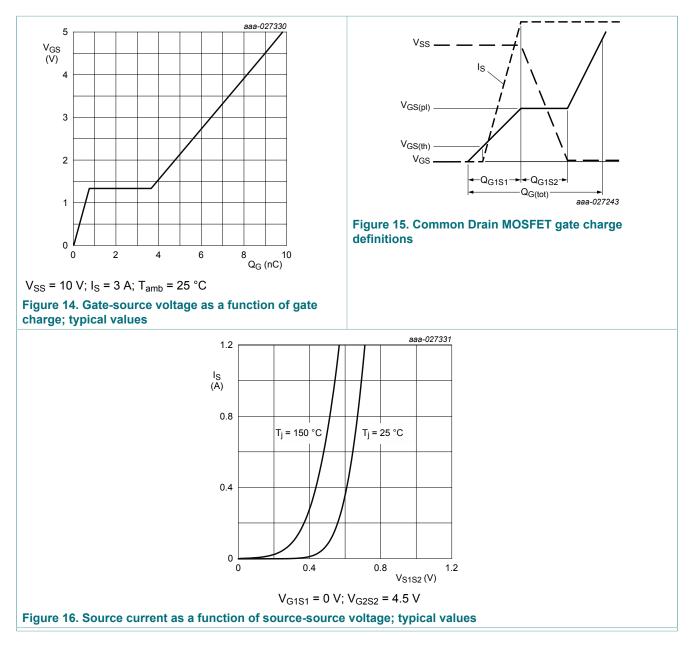


PMCM650CUNE

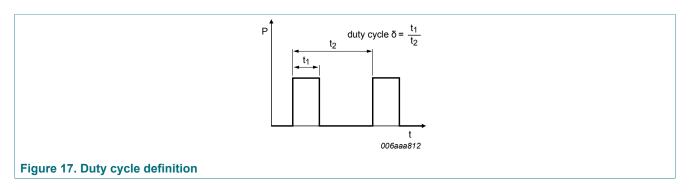


PMCM650CUNE

20 V, Common Drain N-channel Trench MOSFET

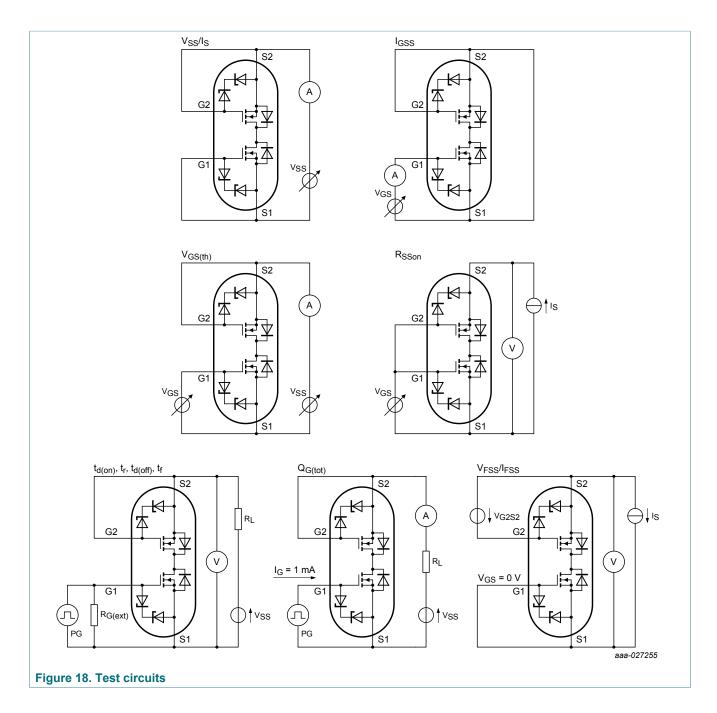


8 Test information



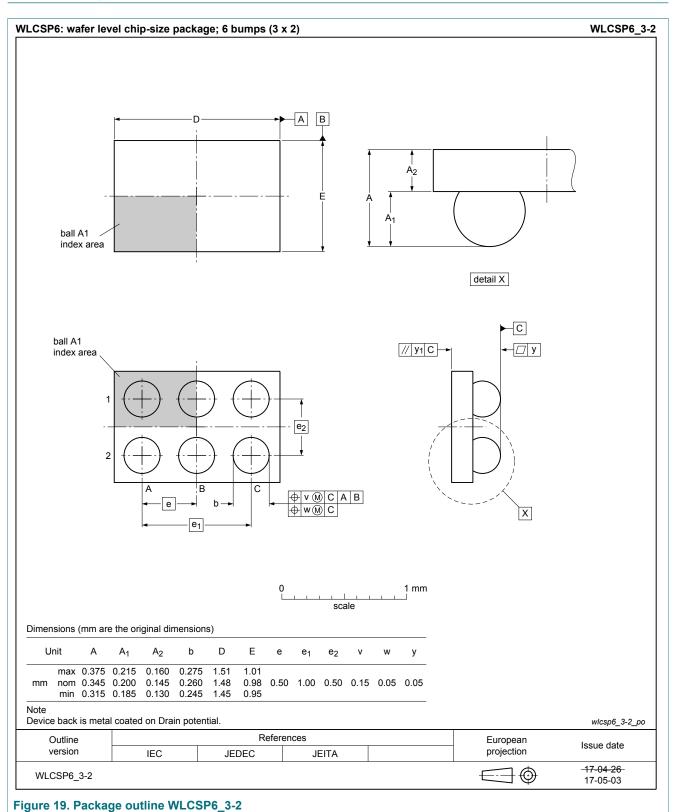
PMCM650CUNE v.1 Product data sheet © Nexperia B.V. 2017. All rights reserved.

PMCM650CUNE



20 V, Common Drain N-channel Trench MOSFET

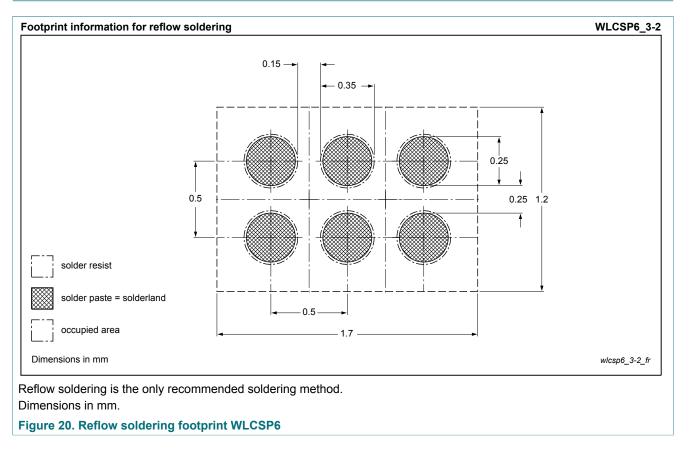
9 Package outline



PMCM650CUNE v.1 Product data sheet

20 V, Common Drain N-channel Trench MOSFET

10 Soldering



20 V, Common Drain N-channel Trench MOSFET

11 Revision history

Table 8. Revision history				
Document ID	Release date	Data sheet status	Change notice	Supersedes
PMCM650CUNE v.1	20171108	Product data sheet	-	-

20 V, Common Drain N-channel Trench MOSFET

12 Legal information

12.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

Please consult the most recently issued document before initiating or completing a design. [1]

The term 'short data sheet' is explained in section "Definitions".

[2] [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nexperia.com.

12.2 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. Nexperia does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local Nexperia sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

Product specification — The information and data provided in a Product data sheet shall define the specification of the product as agreed between Nexperia and its customer, unless Nexperia and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the Nexperia product is deemed to offer functions and qualities beyond those described in the Product data sheet.

12.3 Disclaimers

Limited warranty and liability - Information in this document is believed to be accurate and reliable. However, Nexperia does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. Nexperia takes no responsibility for the content in this document if provided by an information source outside of Nexperia. In no event shall Nexperia be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory. Notwithstanding any damages that customer might incur for any reason whatsoever, Nexperia's aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the Terms and conditions of commercial sale of Nexperia

Right to make changes - Nexperia reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use - Nexperia products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of an Nexperia product can reasonably be expected to result in personal injury, death or severe property or environmental damage. Nexperia and its suppliers accept no liability for inclusion and/or use of Nexperia products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. Nexperia makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification. Customers are responsible for the design and operation of their applications and products using Nexperia products, and Nexperia accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the Nexperia product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products. Nexperia does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using Nexperia products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). Nexperia does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale - Nexperia products are sold subject to the general terms and conditions of commercial sale, as published at http://www.nexperia.com/profile/terms, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. Nexperia hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of Nexperia products by customer

No offer to sell or license - Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

20 V, Common Drain N-channel Trench MOSFET

Non-automotive qualified products — Unless this data sheet expressly states that this specific Nexperia product is automotive qualified, the product is not suitable for automotive use. It is neither qualified nor tested in accordance with automotive testing or application requirements. Nexperia accepts no liability for inclusion and/or use of non-automotive qualified products in automotive equipment or applications. In the event that customer uses the product for design-in and use in automotive applications to automotive specifications and standards, customer (a) shall use the product without Nexperia's warranty of the product for such automotive applications, use and specifications beyond Nexperia's specifications such use shall be solely at customer's own risk, and (c) customer fully indemnifies Nexperia for any liability, damages or failed product claims resulting from customer

design and use of the product for automotive applications beyond Nexperia's standard warranty and Nexperia's product specifications.

Translations — A non-English (translated) version of a document is for reference only. The English version shall prevail in case of any discrepancy between the translated and English versions.

12.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

20 V, Common Drain N-channel Trench MOSFET

Tables

Tab. 1.	Quick reference data	.1
Tab. 2.	Pinning	2
Tab. 3.	Ordering information	2
Tab. 4.	Marking codes	.2

Figures

Normalized total power dissipation as a
function of junction temperature4
Normalized continuous source-source
current as a function of junction temperature 4
Safe operating area; junction to ambient;
continuous and peak source currents as a
function of source-source voltage
Transient thermal impedance from junction
to ambient as a function of pulse duration;
typical values5
Transient thermal impedance from junction
to ambient as a function of pulse duration;
typical values6
Output characteristics: source current as a
function of source-source voltage; typical
values8
Sub-threshold source current as a function
of gate-source voltage8
Source-source on-state resistance as a
function of source current; typical values
Source-source on-state resistance as a
function of gate-source voltage; typical
values8

Tab. 5.	Limiting values	3
	Thermal characteristics	
Tab. 7.	Characteristics	7
Tab. 8.	Revision history	. 14

Fig. 10.	Transfer characteristics: drain current as a function of gate-source voltage; typical values	9
Fig. 11.	Normalized source-source on-state	0
	resistance as a function of junction	0
Fig. 12.	temperature; typical values Gate-source threshold voltage as a function	9
1 ly. 12.	of junction temperature	q
Fig. 13.	Input, output and reverse transfer	5
r ig. 10.	capacitances as a function of source-source	
	voltage; typical values	9
Fig. 14.	Gate-source voltage as a function of gate	
0	charge; typical values	10
Fig. 15.	Common Drain MOSFET gate charge	
•	definitions	10
Fig. 16.	Source current as a function of source-	
	source voltage; typical values	
Fig. 17.	Duty cycle definition	10
Fig. 18.	Test circuits	11
Fig. 19.	Package outline WLCSP6_3-2	12
Fig. 20.	Reflow soldering footprint WLCSP6	13

PMCM650CUNE

20 V, Common Drain N-channel Trench MOSFET

Contents

1	Product profile	
1.1	General description	1
1.2	Features and benefits	1
1.3	Applications	1
1.4	Quick reference data	1
2	Pinning information	2
3	Ordering information	
4	Marking	2
5	Limiting values	3
6	Thermal characteristics	5
7	Characteristics	7
8	Test information	10
9	Package outline	12
10	Soldering	13
11	Revision history	
12	Legal information	

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.

© Nexperia B.V. 2017.

All rights reserved.

For more information, please visit: http://www.nexperia.com For sales office addresses, please send an email to: salesaddresses@nexperia.com

Date of release: 8 November 2017 Document identifier: PMCM650CUNE v.1